



# CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

## SMALL FLAT PNP Epitaxial Transistor

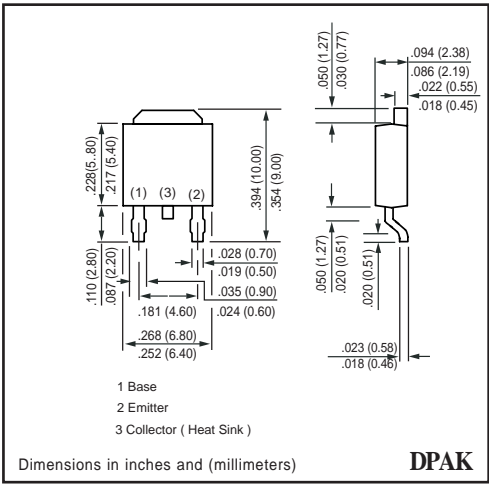
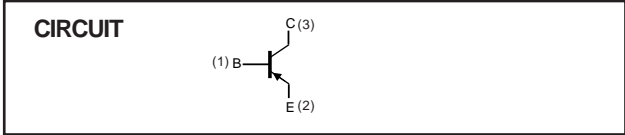
VOLTAGE 32 Volts CURRENT 2 Ampere

**2SB1182GP**

**APPLICATION**  
\* Power driver and Dc to DC convertor .

**FEATURE**  
\* Small flat package. ( DPAK )  
\* PC= 1.5 W (mounted on ceramic substrate).  
\* High saturation current capability.

**CONSTRUCTION**  
\* PNP Switching Transistor



**MAXIMUM RATINGS** ( At TA = 25°C unless otherwise noted )

RATINGS	CONDITION	SYMBOL	MIN.	MAX.	UNITS
Collector - Base Voltage	Open Emitter	VCBO	-	-40	Volts
Collector - Emitter Voltage	Open Base	VCEO	-	-32	Volts
Emitter - Base Voltage	Open Collector	VEBO	-	-5	Volts
Collector Current DC		IC	-	-2	Amps
Peak Collector Current		ICM	-	-3	Amps
Peak Base Current		IBM	-	-0.5	Amps
Total Power Dissipation	TA ≤ 25°C; Note 1	PTOT	-	1500	mW
Storage Temperature		TSTG	-55	+150	°C
Junction Temperature		TJ	-	+150	°C
Operating Ambient Temperature		TAMB	-55	+150	°C

**Note**

1. Transistor mounted on ceramic substrate 50mmX50mmX0.8t.
2. Measured at Pulse Width 300 us, Duty Cycle 2%.

## RATING CHARACTERISTIC CURVES ( 2SB1182GP )

**CHARACTERISTICS** ( At  $T_A = 25^\circ\text{C}$  unless otherwise noted )

PARAMETERS	CONDITION	SYMBOL	MIN.	TYPE	MAX.	UNITS
Collector Cut-off Current	$I_E=0; V_{CB}=-20\text{V}$	$I_{CBO}$	-	-	-1.0	$\mu\text{A}$
Emitter Cut-off Current	$I_C=0; V_{EB}=-4\text{V}$	$I_{EBO}$	-	-	-1.0	$\mu\text{A}$
DC Current Gain	$V_{CE}=-3\text{V}$ ; Note 1 $I_C=-0.5\text{A}$	$h_{FE}$	82	-	390	
Collector-Emitter Saturation Voltage	$I_C=-2\text{A}; I_B=-0.2\text{A}$	$V_{CEsat}$	-	-0.3	-0.5	Volts
Base-Emitter Saturatio Voltage	$I_C=-2\text{A}; I_B=-0.2\text{A}$	$V_{BEsat}$	-	-1.0	-1.5	Volts
Collector Capacitance	$I_E=I_C=0; V_{CB}=-10\text{V}$ ; $f=1\text{MHz}$	$C_C$	-	55	-	$\text{pF}$
Transition Frequency	$I_C=-0.1\text{A}; V_{CE}=-5.0\text{V}$ ; $f=100\text{MHz}$	$f_T$	-	100	-	$\text{MHz}$

**Note :**

1. Pulse test:  $t_p \leq 300\mu\text{Sec}$ ;  $\delta \leq 0.02$ .

# RATING CHARACTERISTIC CURVES ( 2SB1182GP )

## Typical Electrical Characteristics

Figure 1.  $C_c$  - Reverse  $V_{cb}$

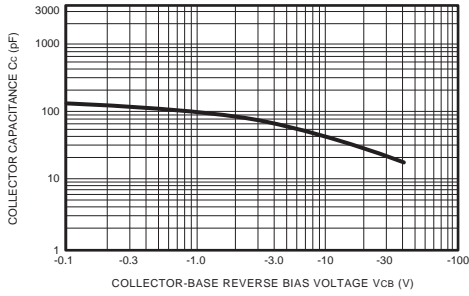


Figure 2. Cutoff Frequency -  $I_c$

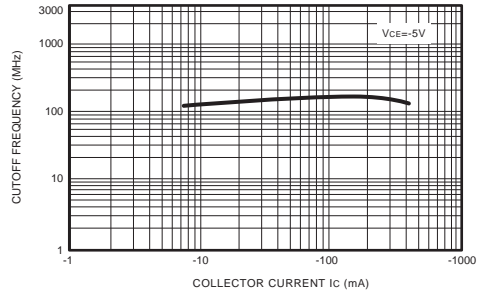


Figure 3.  $h_{FE}$  -  $I_c$

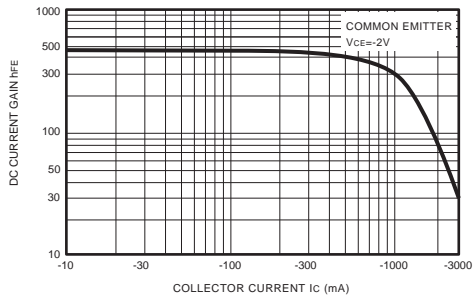


Figure 4.  $P_c$  -  $T_a$

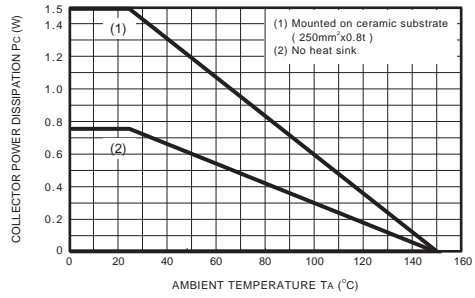


Figure 5.  $V_{CE(sat)}$  -  $I_c$

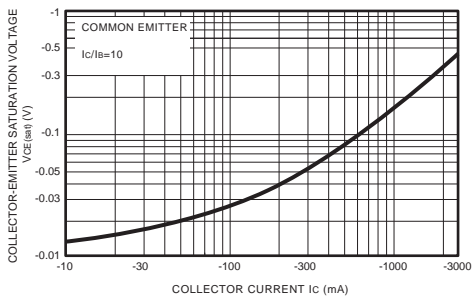


Figure 6.  $V_{BE(sat)}$  -  $I_c$

